NPN Epitaxial Planar Silicon Transistor



2SC5231

# VHF to UHF Wide-Band Low-Noise Amplifier Applications

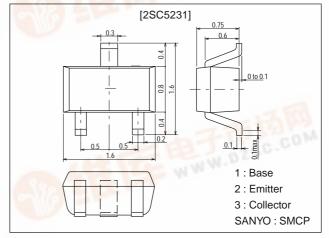
#### **Features**

- · Low noise : NF=1.0dB typ (f=1GHz).
- · High gain :  $|S21e|^2=12dB$  typ (f=1GHz).
- · High cutoff frequency : f<sub>T</sub>=7GHz typ.
- · Very small-sized package permiting 2SC5231-applied sets to be made small and slim.

## **Package Dimensions**

unit:mm

2106A



Continued on next page.

# **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		20	V
Collector-to-Emitter Voltage	VCEO		10	V
Emitter-to-Base Voltage	V <sub>EBO</sub>	140	2	V
Collector Current	I <sub>C</sub>		70	mA
Collector Dissipation	PC	and Committee	100	mW
Junction Temperature	Tj	AND AND THE V	150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Symbol Conditions		Ratings		
Faranielei	Symbol			typ	max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0			1.0	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =1V, I <sub>C</sub> =0			10	μA
DC Current Gain	hFE	V <sub>CE</sub> =5V, I <sub>C</sub> =20mA	60*		270*	
Gain-Bandwidth Product	fT	V <sub>CE</sub> =5V, I <sub>C</sub> =20mA	5	7		GHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz	J-1	0.7	1.2	pF
Reverse Transfer Capacitance	Cre	V <sub>CB</sub> =10V, f=1MHz		0.45	2v.	pF

≠: Pulse Test Pulse Width≤2ms

\* : The 2SC5231 is classified by 20mA  $h_{FE}$  as follows :

 Marking
 C7
 C8
 C9

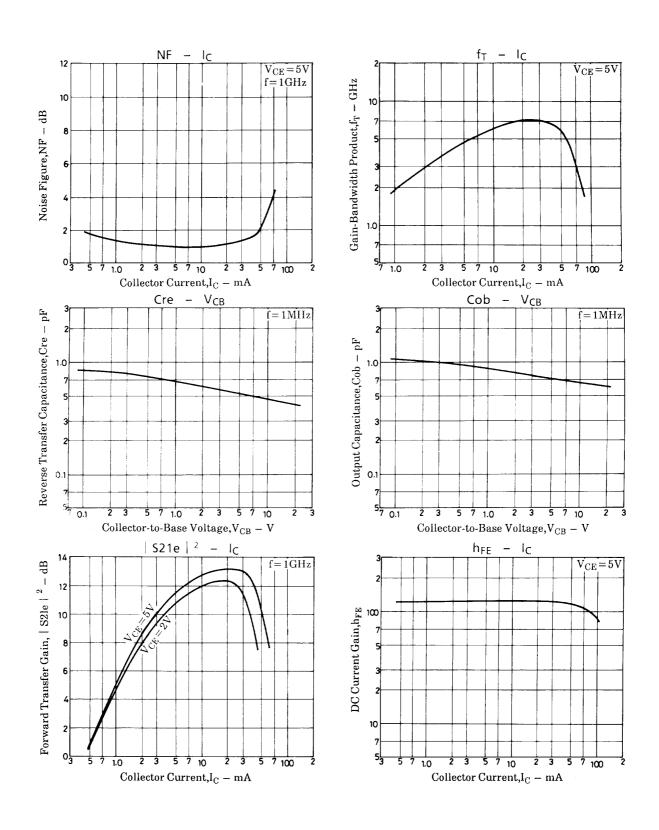
 hFE
 60 to 120
 90 to 180
 135 to 270

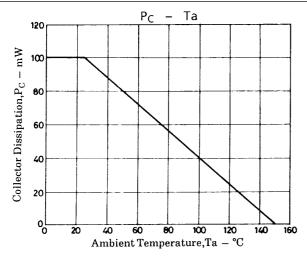
- Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.
- SANYO assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO products described or contained herein.

# SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters

#### Continued from preceding page.

Parameter	Symbol	Conditions		Ratings		
i arameter	Symbol			typ	max	Unit
Forward Transfer Gain	S21e   <sup>2</sup> 1	V <sub>CE</sub> =5V, I <sub>C</sub> =20mA, f=1GHz	9	12		dB
	S21e   <sup>2</sup> 2	V <sub>CE</sub> =2V, I <sub>C</sub> =3mA, f=1GHz		8.5		dB
Noise Figure	NF	V <sub>CE</sub> =5V, I <sub>C</sub> =7mA, f=1GHz		1.0	1.8	dB

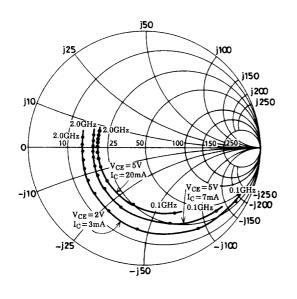


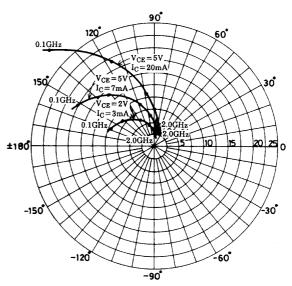


#### **S Parameters**

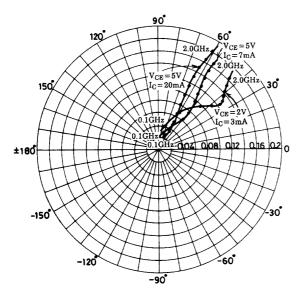
S11e: f=100MHz,  $200\sim2000MHz$  (200MHz step)

S21e: f = 100MHz,  $200 \sim 2000MHz$  (200MHz step)

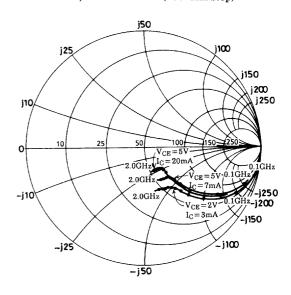




S12e : f = 100MHz,  $200 \sim 2000MHz$  (200MHz step)



S22e: f=100MHz,  $200\sim2000MHz$  (200MHz step)



# 2SC5231

### **S parameters** (Common emitter)

 $V_{CE}$ =5V,  $I_{C}$ =7mA,  $Z_{O}$ =50 $\Omega$ 

Freq (MHz)	S <sub>11</sub>	∠S <sub>11</sub>	S <sub>21</sub>	∠S <sub>21</sub>	S <sub>12</sub>	∠S <sub>12</sub>	S <sub>22</sub>	∠ S <sub>22</sub>
100	0.786	-40.7	17.507	151.3	0.028	70.1	0.898	-20.4
200	0.677	-72.4	13.998	131.4	0.046	58.0	0.739	-33.4
400	0.546	-112.7	9.061	108.6	0.064	49.6	0.525	-43.7
600	0.492	-135.2	6.442	96.1	0.076	49.3	0.432	-46.7
800	0.473	-150.0	5.005	87.3	0.087	50.8	0.374	-44.4
1000	0.465	-160.0	4.073	80.4	0.099	52.6	0.346	-49.7
1200	0.457	-169.5	3.449	74.0	0.111	54.0	0.332	-51.6
1400	0.451	-176.2	2.989	68.6	0124	55.2	0.321	-54.1
1600	0.449	177.8	2.658	63.8	0.138	56.6	0.319	-56.2
1800	0.454	172.5	2.378	58.4	0.151	56.7	0.313	-60.0
2000	0.460	167.1	2.154	54.0	0.166	56.7	0.311	-63.2

# $V_{\text{CE}}\!\!=\!\!5\text{V}\!,\,I_{\text{C}}\!\!=\!\!20\text{mA},\,Z_{\text{O}}\!\!=\!\!50\Omega$

Freq (MHz)	S <sub>11</sub>	∠S <sub>11</sub>	S <sub>21</sub>	∠S <sub>21</sub>	S <sub>12</sub>	∠S <sub>12</sub>	S <sub>22</sub>	∠ S <sub>22</sub>
100	0.601	-65.8	28.967	137.1	0.023	64.1	0.757	-32.9
200	0.497	-103.7	19.309	116.6	0.035	57.0	0.534	-50.3
400	0.435	-139.6	10.891	98.6	0.050	58.7	0.345	-50.3
600	0.419	-156.6	7.461	89.3	0.065	61.3	0.280	-50.7
800	0.414	-166.6	5.695	82.5	0.081	63.1	0.251	-51.3
1000	0.413	-174.0	4.613	77.0	0.098	63.8	0.235	-52.9
1200	0.413	178.6	3.870	71.8	0.114	63.9	0.226	-55.1
1400	0.411	173.8	3.345	66.9	0.131	63.6	0.221	-57.7
1600	0.413	169.6	2.960	62.7	0.148	63.2	0.220	-60.2
1800	0.416	165.1	2.655	58.0	0.165	61.8	0.219	-64.8
2000	0.422	160.3	2.406	54.0	0.182	60.6	0.218	-68.3

#### $V_{CE}\!\!=\!\!2V\!,\,I_{C}\!\!=\!\!3mA,\,Z_{O}\!\!=\!\!50\Omega$

Freq (MHz)	S <sub>11</sub>	∠S <sub>11</sub>	S <sub>21</sub>	∠S <sub>21</sub>	S <sub>12</sub>	∠S <sub>12</sub>	S <sub>22</sub>	∠S <sub>22</sub>
100	0.888	-30.2	9.280	158.6	0.038	73.6	0.949	-15.1
200	0.815	-56.4	8.218	141.3	0.067	60.5	0.849	-26.9
400	0.690	-96.0	6.074	116.7	0.098	45.1	0.657	-41.1
600	0.616	-120.7	4.517	101.4	0.112	38.4	0.539	-47.6
800	0.584	-138.0	3.610	90.4	0.120	35.8	0.475	-51.2
1000	0.566	-150.7	2.995	81.9	0.125	35.7	0.434	-54.5
1200	0.555	-161.2	2.540	74.2	0.131	36.5	0.410	-57.5
1400	0.546	-169.3	2.213	67.5	0.137	38.4	0.393	-60.7
1600	0.541	-176.4	1.982	62.0	0.143	40.7	0.391	-64.0
1800	0.545	177.1	1.774	55.9	0.152	42.5	0.382	-67.8
2000	0.547	170.9	1.614	50.9	0.163	44.7	0.381	-72.1

- Specifications of any and all SANYO products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Electric Co., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of SANYO Electric Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of February, 1999. Specifications and information herein are subject to change without notice.